Schottky Barrier Diode

These Schottky barrier diodes are designed for high–speed switching applications, circuit protection, and voltage clamping. Extremely low forward voltage reduces conduction loss. Miniature surface mount package is excellent for hand–held and portable applications where space is limited.

Features

- Extremely Fast Switching Speed
- Extremely Low Forward Voltage 0.28 V (Typ) @ $I_F = 1.0$ mAdc
- Low Reverse Current
- Lead–Free Plating
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- These Devices are Pb–Free, Halogen Free/BFR Free and are RoHS Compliant

MAXIMUM RATINGS

Rating	Symbol	Value	Unit		
Peak Reverse Voltage	V _{RM}	40	V		
Reverse Voltage	V _R	30	V		
Forward Continuous Current (DC)	١ _F	30	mA		
Peak Forward Surge Current	I _{FSM} 500		mA		
ESD Rating: Class 1C per Human Body Model Class A per Machine Model					

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit	
Total Device Dissipation FR–5 Board, (Note 1) $T_A = 25^{\circ}C$	PD	200	mW	
Derate above 25°C		1.57	mW/°C	
Thermal Resistance, Junction-to-Ambient	R_{\thetaJA}	635	°C/W	
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C	

1. FR-5 Minimum Pad.



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40 V SCHOTTKY BARRIER DIODE





CASE 502 STYLE 1

MARKING DIAGRAM



5E = Specific Device Code M = Date Code

= Pb–Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
RB751S40T1G	SOD-523 (Pb-Free)	3000 / Tape & Reel
NSVRB751S40T1G	SOD-523 (Pb-Free)	3000 / Tape & Reel
RB751S40T5G	SOD-523 (Pb-Free)	8000 / Tape & Reel
NSVRB751S40T5G	SOD-523 (Pb-Free)	8000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

RB751S40

ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

Characteristic	Symbol	Min	Тур	Max	Unit
Reverse Breakdown Voltage (I _R = 10 μA)	V _{(BR)R}	30	-	-	V
Total Capacitance (V _R = 1.0 V, f = 1.0 MHz)	CT	-	2.0	2.5	pF
Reverse Leakage (V _R = 30 V)	I _R	-	300	500	nAdc
Forward Voltage (I _F = 1.0 mAdc)	V _F	-	0.28	0.37	Vdc

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.



Voltage



Figure 3. Typical Capacitance